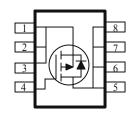
## P-Channel 40-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low  $r_{DS(on)}$  and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

PRODUCT SUMMARY				
V <sub>DS</sub> (V)	$r_{DS(on)} m(\Omega)$ $I_D(A)$			
-40	$35 @ V_{GS} = -10V$	-9.0		
	45 @ V <sub>GS</sub> = -4.5V	-7.2		

- $\hbox{-} \qquad \text{Low $r_{DS(on)}$ provides higher efficiency and} \\ \text{extends battery life}$
- Low thermal impedance copper leadframe SOIC-8 saves board space
- Fast switching speed
- High performance trench technology





ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25 °C UNLESS OTHERWISE NOTED)					
Parameter			Maximum	Units	
Drain-Source Voltage			-40	V	
Gate-Source Voltage			±20	V	
Continue Durin Commut <sup>a</sup>	$T_A=25^{\circ}C$	T	-9.0	_	
Continuous Drain Current <sup>a</sup>	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$		-7.3	A	
Pulsed Drain Current <sup>b</sup>			±50		
Continuous Source Current (Diode Conduction) <sup>a</sup>			-2.1	A	
Decree Discipation <sup>8</sup>	$T_A=25^{\circ}C$	D	3.1	W	
Power Dissipation <sup>a</sup>	$T_A=25$ °C $T_A=70$ °C		2.6		
Operating Junction and Storage Temperature Range		$T_J, T_{stg}$	-55 to 150	°C	

THERMAL RESISTANCE RATINGS						
Parameter	Symbol	Maximum	Units			
M · I · · · · · · · · · a	t <= 10 sec	$R_{ heta JA}$	50	°C/W		
Maximum Junction-to-Ambient <sup>a</sup>	Steady State		92	°C/W		

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## Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

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Parameter	Symbol	Took Conditions	Limits			T T 24	
rarameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = -250 \text{ uA}$	-1				
Gate-Body Leakage	$I_{GSS}$	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 25 \text{ V}$			±100	nA	
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = -24 \text{ V}, V_{GS} = 0 \text{ V}$			-1	uA	
Zero Gate Voltage Drain Current	IDSS	$V_{DS} = -24 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			-5	uA	
On-State Drain Current <sup>A</sup>	$I_{D(on)}$	$V_{DS} = -5 \text{ V}, V_{GS} = -10 \text{ V}$	-50			A	
Drain-Source On-Resistance <sup>A</sup>	r <sub>DS(on)</sub>	$V_{GS} = -10 \text{ V}, I_D = -9.0 \text{ A}$			35 ms		
Drain-Source On-Resistance		$V_{GS} = -4.5 \text{ V}, I_D = -7.2 \text{ A}$			45	1112.2	
Forward Tranconductance <sup>A</sup>	$g_{\mathrm{fs}}$	$V_{DS} = -15 \text{ V}, I_D = -9.0 \text{ A}$		31		S	
Diode Forward Voltage	$V_{\mathrm{SD}}$	$I_S = -2.1 \text{ A}, V_{GS} = 0 \text{ V}$		-0.7		V	
Dynamic <sup>b</sup>							
Total Gate Charge	$Q_{g}$	V = 15 V V = 45 V		15.3			
Gate-Source Charge	$Q_{gs}$	$V_{DS} = -15 \text{ V}, V_{GS} = -4.5 \text{ V},$ $I_{D} = -9.0 \text{ A}$		5.2		nC	
Gate-Drain Charge	$Q_{gd}$	I <sub>D</sub> = -9.0 A		5.8			
Turn-On Delay Time	t <sub>d(on)</sub>			15			
Rise Time	t <sub>r</sub>	$V_{DD} = -15 \text{ V}, R_L = 15 \Omega, I_D = -1 \text{ A},$		12		nS	
Turn-Off Delay Time	$t_{d(off)}$	$V_{GEN} = -10 \text{ V}, R_G = 6\Omega$		62		ns	
Fall-Time	$t_{\mathrm{f}}$			46			

## Notes

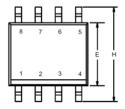
- a. Pulse test:  $PW \le 300us duty cycle \le 2\%$ .
- b. Guaranteed by design, not subject to production testing.

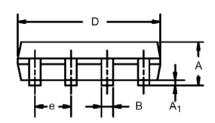
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## Package Information

SO-8: 8LEAD





	MILLIN	IETERS	INCHES	
Dim	Min	Max	Min	Max
Α	1.35	1.75	0.053	0.069
A <sub>1</sub>	0.10	0.20	0.004	0.008
В	0.35	0.51	0.014	0.020
С	0.19	0.25	0.0075	0.010
D	4.80	5.00	0.189	0.196
E	3.80	4.00	0.150	0.157
е	1.27 BSC		0.050 BSC	
Н	5.80	6.20	0.228	0.244
h	0.25	0.50	0.010	0.020
L	0.50	0.93	0.020	0.037
q	0°	8°	0°	8°

